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In controlling the thermal properties of the surrounding environment, we provide insight into the underlying mechanisms driving the widely used laser direct write method for additive manufacturing. We find that the onset of silver nitrate reduction for the formation of direct write structures directly corresponds to the calculated steady-state temperature rises associated with both continuous wave and high-repetition rate, ultrafast pulsed laser systems. Furthermore, varying the geometry of the heat affected zone, which is controllable based on in-plane thermal diffusion in the substrate, and laser power, allows for control of the written geometries without any prior substrate preparation. These findings allow for the advance of rapid manufacturing of micro- and nanoscale structures with minimal material constraints through consideration of the laser-controllable thermal transport in ionic liquid/substrate media. Published by AIP Publishing. https://doi.org/10.1063/1.5016073

Major technological advancements in the last few decades have relied on the ability to continuously decrease the size of devices. In doing so, a dependence on manufacturing processes to enhance their spatial resolutions has grown significantly.1–4 Optical-based techniques have been at the forefront of these processes due to the decreased length-scales associated with the ability to selectively expose materials to photon irradiation. Photolithography, for example, has been the foundation of micro- and nanoscale integrated circuits1,3 due to its increased spatial resolution and material compatibilities compared to typical additive manufacturing techniques (e.g., 3D printing of thermoplastics or even biomaterials).4–6 Yet, photolithographic processes are highly limited in material capabilities/specificities as well as processing times. For example, clean-room photolithography is limited to electronic materials on a small range of substrates. Techniques that aim to address such limitations include laser-induced forward transfer (LIFT),4–7 laser-sintering,8,9 and multi-photon polymerization methods.4,8–11

LIFT overcomes many material limitations and is primarily used for deposition of metals and oxides.12 Other advancements, such as the introduction of matrix-assisted laser evaporation in the direct write process (MAPLE-DW),7 have expanded these limitations, providing the ability to create structures with far more complex materials, such as biological specimens.13 Nonetheless, this method is not rapid enough for prototyping or mass-scale manufacturing. Furthermore, the formed structures are much larger than those created by other methods and are formed solely on planar supports. These two drawbacks arise from the requirement of a ribbon placed above the desired substrate; the formation of the ribbon is a non-trivial task, since the desired material must be pre-formed as a thin film with consistent morphology. As the ribbon must be parallel at all desired writing points on the substrate, two planar geometries are a necessity. Thus, this method does not allow for complex 3-dimensional structures (the ribbon is consistently removed in blocks of the same size/morphology). On the other hand, laser-sintering is far less limited in geometries available, as a laser interacts with a pre-deposited powder or ink on the substrate of choice; this interaction anneals the colloidal particles or powder to form prescribed micro- and nano-structures.8,9 This process, however, is known to form structures with a large density of defects and poorly defined edges, as the annealing process reaches critical temperatures in the ink environment, leading to cavitation and uncontrolled growth processes.14 Multi-photon polymerization overcomes many of the aforementioned geometry and resolution constraints, as multi-photon processes inherently occur in small volumes,15–17 but is highly limited to select materials.

Within each laser-based method, thermal effects are consistently investigated throughout the literature.4,8–11 Unfortunately, many investigations fail to provide concrete evidence of a diffusive thermal process initiating and/or driving the laser writing process. For example, previous investigations involving laser direct write from silver nitrate solutions (AgNO3) reference photo-reduction,20 multiphoton absorption,16 and even non-equilibrium growth21 as potential factors that ultimately lead to the formation of silver structures.

As a more universally applicable phenomenon, we investigate the role of the absorbed energy from the laser source, substrate thermal conductivity, and resulting thermal transport in silver metal line fabrication during laser direct write on a variety of substrates submerged in an ionic liquid precursor. In our previous work, we have surmised that the local energy density and the resulting steady-state temperature rise from an
absorbed laser source drive the thermal direct write process and hence increase the generality and expand the material applicability of laser direct writing. With the goal of producing material structures across the periodic table, wet-chemistry techniques have unveiled the proper precursor solutions for most materials.

We hypothesize that direct control over the decomposition of the ionic liquid can be achieved through the control of heat dissipation through the substrate to limit the steady-state temperature rise resulting from the laser substrate interaction. This decomposition ultimately leads to nucleation of ions, resulting in deposition of Ag structures. This thermal activation allows for universal material deposition, in terms of both the formed structure and underlying substrate, as the sole requisite for decomposition is a sufficient rise in temperature. In principle, this process theoretically allows for sub-diffraction sized structures, similar to multi-photon polymerization, which is considered to be at the forefront of spatial resolution, as the decomposition threshold can be reached solely at the peak of the Gaussian spatial temperature distribution. Thus, the ability to control thermal directly written nanostructures via absorbed energy density that is driven by the laser source and substrate/liquid media thermal properties provides the potential to expand the current limits of fabrication of nano-materials and hierarchical devices.

Our laser direct write method used for this work relies on a continuous-wave (CW) 532 nm laser that is focused to a 15 μm 1/e² radius to form metallic Ag structures from a 0.1 M AgNO₃ ionic precursor; details on the ionic precursor preparation, as well as a diagram and additional details on the experimental setup, are included in the supplementary material. The peak-power density of this beam is orders of magnitude too low for multi-photon processes, such as two-photon polymerization or multi-photon absorption to occur, eliminating their potential role in the formation of Ag structures. Furthermore, thermal dissipation and accumulation of the absorbed energy density leading to steady-state temperature rises at the solid-liquid interface are more easily quantified with knowledge of CW laser source power densities; for pulsed light sources, the large instantaneous temperature rise associated with individual pulses complicates the thermal aspect of our analysis. Thus, in this work, we use our CW 532 nm laser to demonstrate the role of steady-state temperature rises—governed by the laser power and substrate thermal conductivity—in the ability to thermally direct write metal lines on the substrate surface. As AgNO₃ has been widely studied in additive manufacturing techniques have unveiled the proper precursor solutions for most materials. We write metallic lines from laser irradiation of AgNO₃ solutions on three different substrates (amorphous SiO₂ “glass,” crystalline SiO₂ “quartz,” and crystalline Al₂O₃ “sapphire”) with similar absorption coefficients at 532 and attempt to write Ag on a range of substrates with varying thermal properties and find that the process can be optimized based on steady-state temperature rises from either the power from the CW beam or the average accumulation of the power from the laser pulses in the case of our pulsed source.

The average power from the laser absorbed on the surface of a material results in a steady-state temperature rise. We can approximate this temperature rise, ΔT, from the multilayer solution to the radially symmetric heat equation with a periodic Gaussian heat source absorbed at the surface or interface, given by

\[ \Delta T = 2\pi P_0 \int_0^\infty G(k) \exp \left( -\frac{\pi^2 k^2 r_0^2}{4} \right) kd\eta, \]

where \( P_0 \) is the absorbed laser power, \( r_0 \) is the radius of the incident beam, and \( G(k) \) is the Hankel transform of the radially symmetric heat equation in a multilayer system with semi-infinite substrates. In relation to this work, this function takes into account both the thermal conductivity and the volumetric heat capacity of the substrate and overlying ionic liquid precursor and is explained in detail in prior works. In the pulsed case, individual pulses are capable of much larger, impulse temperature rises on the surface in a time frame on the order of the pulse width and subsequent carrier nonequilibrium relaxation times in the material; the temperature rises associated with individual pulses are likely not a determining factor for thermal-direct write processes as the nucleation and growth mechanisms for ionic reduction occur on much larger time scales than the pulse duration used in this experiment (<500 fs); rather, the steady-state rise due to thermal accumulation from the high-repetition rate is expected to be primary mechanism for such processes. Previous experimental observations for rapid particle formation via precipitation have been measured via small-angle x-ray scattering, and formation is found to occur on the order of 10⁻⁴ of μs, with further growth limited by mass transfer. Furthermore, previous experiments in laser driven reduction have found growth to be affected by thermal accumulation at times greater than 1 μs (note: this value was determined from AgNO₃ in a gelatin matrix, where it is also predicted that negligible thermal effects occur at repetition rates of 1 MHz). Similar high-energy thermal methods for particle synthesis in liquids, such as short-pulse laser ablation, have determined the growth of nanoparticles to occur on similar time scales. Thus, one would predict only the cumulative effect due to multiple pulses to play a role in thermal decomposition of the ionic precursor. We find a direct correlation between the temperature rise from energy accumulation of the absorbed laser beam [Eq. (1)] and the formation of structures via reduction of AgNO₃. Thus, the hypothesis that steady-state temperature rises play the dominant role in thermal direct write, which we show is directly related to the thermal conductivity of the substrate, is further reinforced in comparing fabrication conditions between the pulsed and CW laser sources.

We write metallic lines from laser irradiation of AgNO₃ solutions on three different substrates (amorphous SiO₂ “glass,” crystalline SiO₂ “quartz,” and crystalline Al₂O₃ “sapphire”) with similar absorption coefficients at 532 and
680 nm and a constant spot-size of ~15 μm. This greatly simplifies our thermal analysis as the steady-state temperature rise at the solid-liquid interface is dictated solely by the thermal conductivities of the fluid and substrate, as determined via Eq. (1). The resulting line-width is plotted as a function of substrate thermal conductivity in Fig. 1 for a fixed laser power density. As shown, with increasing thermal conductivity, there is a nearly linear decrease in measured line-width due to the reduced temperature rise on the substrate surface.

This posit is further supported through the measured power density thresholds to induce the direct write process with each substrate; one should expect equivalent temperature rises necessary to decompose the AgNO₃ to form metallic Ag regardless of the substrate. The measured threshold necessary to form metallic Ag structures is shown in Fig. 2. In calculating these power densities, we assume ~5% absorption near the substrate precursor interface; as the laser may have increased absorption due to initial structure formation (i.e., the deposited Ag line will have enhanced absorption compared to the nearly transparent substrate), this value may be variable during the deposition process, but we expect any variability to be consistent across all substrates. This assumption is based on the extinction spectra associated with Ag nanoparticles formed from photoreduction; although considerably far from the absorption peak associated with their surface plasmon resonance, the extinction does not go to zero at 532 nm. 38–40 Additionally, silver-ion based solutions are known to have non-zero absorption at visible wavelengths. 41,42 At a lower absorbed power density, the temperature rise is sufficiently high to laser direct-write structures on substrates with lower thermal conductivities compared to that of the substrate of higher thermal conductivity. We calculate the average steady-state thermal accumulation temperature rise using the thermal conductivities of the glass, quartz, and sapphire substrates measured via time domain thermoreflectance (TDTR) (1.3 W m⁻¹ K⁻¹, 13.5 W m⁻¹ K⁻¹, and 35 W m⁻¹ K⁻¹, respectively). 33,43,44 Furthermore, we estimate the thermal conductivity of the ionic liquid precursor to be 0.24 W m⁻¹ K⁻¹ based on the respective concentrations of water and ethanol (17 and 83 vol. %, respectively). In doing so, we find the maximum temperature rise at the respective power density thresholds to be within 10% of each other on all three substrates, this temperature rise being ~197 K. Note that we reference the maximum temperature rise because it is indicative of the power density at the center of the Gaussian spatial profile associated with our laser beam. This is in reasonable agreement with previous works, where the value for thermal reduction of AgNO₃ has been measured to be as low as 150 °C (equivalent to a ~130 K temperature rise), allowing for at least partial thermal reduction of AgNO₃. 35

To gain further insight into the role of the steady-state temperature risers during the laser induced thermal direct-write processing, we consider the line-widths associated with varying power densities; the measured values obtained from SEM micrographs, such as shown in Fig. 3(a), are depicted in Fig. 3(b) for fused silica and quartz substrates (with thermal conductivities of 1.3 W m⁻¹ K⁻¹ and 13 W m⁻¹ K⁻¹, respectively). As shown, there is a decrease in the width of the line with decreasing power density. This phenomenon has been demonstrated in a few previous works. 28,46 As noted by Lu et al., 46 in the direct writing of Ag by thermal decomposition of CH₃COOAg, the line-width follows the temperature profile induced by the Gaussian beam. In other words, with increased laser power, the temperature threshold necessary for thermal decomposition of the precursor liquid is exceeded at distances farther from the center of the beam profile. This concept is further reinforced through consideration of Eq. (1); we plot the calculated temperature profile as a function of radius from the center of the Gaussian distribution in Fig. 3(c). As can be seen, with increasing power density, the critical temperature rise necessary to induce thermal decomposition of the precursor is obtained at increasing distances from the center of the incident beam. As an additional experiment to vary the steady-state temperature rise and investigate its role during laser thermal direct write manufacturing, we alter the dwell time (i.e., scan velocity) of the incident beam. As discussed in detail in the supplementary material and graphically depicted in Fig. S2, we find a decrease in line-width, or lower induced temperature rise.

![FIG. 1. Measured line-width for Ag microstructures at an absorbed power density of ~350 MW m⁻² for substrates of varying substrate thermal conductivity; these were synthesized with a CW 532 nm beam.](image1)

![FIG. 2. Measured absorbed power density necessary to form Ag microstructures (i.e., power threshold necessary to induce direct write) as a function of thermal conductivity of the substrate using a continuous wave, 532 nm beam.](image2)
across the Gaussian distribution, with decreased dwell times/increased scan velocities, as one would predict via Eq. (1).

Although the role of the substrate thermal conductivity and resulting temperature rise as a method for laser direct writing of nanostructures is clearly demonstrated above, in addition to the fact we utilize a low peak-power, CW beam to negate the potential for multi-photon processes, we cannot rule out an initiation process being driven by photodecomposition of the silver nitrate solution. To gain insight into the role of photodecomposition and further thermal processing, we thermally direct write with a pulsed laser at 680 nm. Additionally, should photoreduction be a prominent mechanism, the reduced photon energy should present different results as compared to the case of the visible light at 532 nm.

In the case of <500 fs pulses heating the sample at a frequency of 1 MHz, we continue to find a similar trend in power thresholds and associated line widths for silver structures on the three substrates with varying thermal conductivities. For example, due to the non-linear processes necessary to reach near-infrared wavelengths through the OPA, the available average power output is limited in this experimental scheme, and we are unable to thermally write structures on sapphire due to its high thermal conductivity and thus low steady-state temperature rise even at the maximum attainable power density. This finding further reinforces the notion of thermal decomposition rather than photodecomposition of the AgNO₃ to metallic Ag. Conversely, glass reaches high enough temperatures for rapid decomposition of AgNO₃ and subsequent nucleation of metallic silver. Crystalline quartz, with an order of magnitude larger thermal conductivity as compared to the SiO₂ glass (and thus lower steady-state temperature rise at the solid-liquid interface), only undergoes partial decomposition of silver nitrate, leading to minimal nucleation.⁴⁵ Although photo-decomposition may be operating in tandem with thermal reduction of the precursor, the agreement between varying wavelengths in both pulsed and continuous-wave lasers implies that the role of thermal accumulation cannot be ignored.

In conclusion, we have demonstrated that thermal accumulation at the solid-liquid interface of the desired substrate and ionic liquid precursor is a primary mechanism for the direct write processing of micro- and nano-structures. Compared to previous works that rely on multi-photon processes, photoresists, and multi-step processing, thermal direct write is a useful one step method for rapid synthesis of well-defined structures as direct write can be achieved simply through the addition of a liquid precursor atop the desired substrate. Additionally, AgNO₃ has previously only been directly written to substrates with an adhesion layer such as a silane-coating added prior to the deposition,¹⁶,³⁵ with thermal direct write, we find that no substrate preparation is necessary. This evidence also provides a future pathway for enhancement and optimization of additive manufacturing techniques relying on laser-material interactions, particularly due to the inherent thermal effects associated with any laser-matter interaction. Through management of thermal dissipation within the laser-induced heat-affected zone, control of morphology, deposition rate, and volume of the formed structure can be controlled with increased precision.

See supplementary material for details on experimental methods including the ionic precursor and substrate preparation procedures, additional details, including a diagram, on the experimental setup, as well as additional information on the characterization performed.


